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View Online at https://aerobasegroup.com/nsn/5961-00-916-0539

Inclosure Material:

Metal

Overall Length:

0.215 inches

Overall Diameter:

0.460 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.138 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 1.00 amperes source cutoff current and 2.50 amperes source cutoff current

Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 uninsulated wire lead and 1 threaded stud

Specification Data:

80131-release4008 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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